UNISONIC TECHNOLOGIES CO., LTD

MGBR20V50 DIODE

MOS GATED BARRIER RECTIFIER

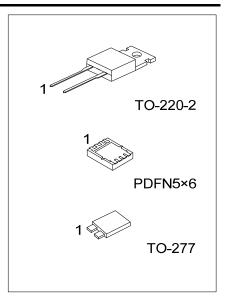
DESCRIPTION

The UTC MGBR20V50 is a surface mount mos gated barrier rectifier, it uses UTC's advanced technology to provide customers with low forward voltage drop and high switching speed etc.

The UTC MGBR20V50 suitable for supply applications.

FEATURES

- * Very low forward voltage drop
- * High switching speed



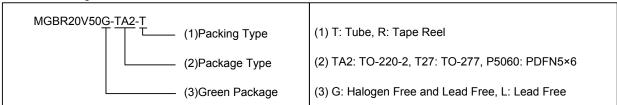
SYMBOL

TO-220-2	TO-277	PDFN5×6				
2 — 1 K	1. A ° 2. K	1. A ° 8. K 2. A ° 7. K 3. A ° 6. K 4. NC ° 5. K				

ORDERING INFORMATION

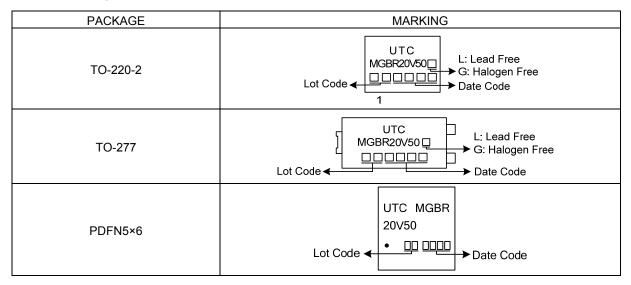
Ordering Number		Dookago	Pin Assignment						Dooking		
Lead Free	Halogen Free	Package	1	2	3	4	5	6	7	8	Packing
MGBR20V50L-TA2-T MGBR20V50G-TA2-T		TO-220-2	Κ	Α	1	-	1	ı	-	1	Tube
MGBR20V50L-T27-R MGBR20V50G-T27-R		TO-277	Α	Κ	Α	-	-	-	-	-	Tape Reel
MGBR20V50L-P5060-R	MGBR20V50G-P5060-R	PDFN5×6	Α	Α	Α	NC	Κ	Κ	Κ	Κ	Tape Reel

Note: Pin Assignment: A: Anode K: Cathode



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■ MARKING



MGBR20V50

■ **ABSOLUTE MAXIMUM RATINGS** (T_A=25°C unless otherwise specified)

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitance load, derate current by 20%.

PARAMETER	SYMBOL	RATINGS	UNIT
DC Blocking Voltage	V_{RM}	50	٧
Working Peak Reverse Voltage	V_{RWM}	50	٧
Peak Repetitive Reverse Voltage	V_{RRM}	50	٧
Average Rectified Forward Current (Rated VR-20Khz Square Wave) - 50% Duty Cycle	Io	20	Α
Peak Forward Surge Current - 1/2 60hz	I _{FSM}	250	Α
Peak Repetitive Reverse Surge Current (2uS-1Khz)	I _{RRM}	2	Α
Maximum Rate of Voltage Change (at Rated V _R)	dv/dt	10000	V/µS
Operating Junction Temperature	T_J	-65 ~ +150	°C
Storage Junction Temperature	T _{STG}	-65 ~ +150	ů

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL DATA

PARAMETER		SYMBOL	RATINGS	UNIT
	TO-220-2		60	
Junction to Ambient	TO-277	θ_{JA}	73 (Note)	°C/W
	PDFN5×6		72	

Note: Mounted on an FR4 PCB, single-sided copper, with 100 cm² copper pad area.

■ **ELECTRICAL CHARACTERISTICS** (T_A=25°C unless otherwise specified)

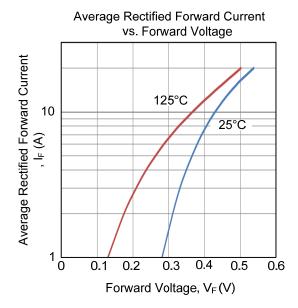
PARAMETER	SYMBOL	TEST CONDITIONS		TYP	MAX	UNIT
Reverse Breakdown Voltage (Note 1)	$V_{(BR)R}$	I _R =0.50mA				V
	V _F	I _F =1A, T _J =25°C		0.29		V
		I _F =1A, T _J =125°C		0.18		V
		I _F =5A, T _J =25°C		0.40		V
Forward Voltage		I _F =5A, T _J =125°C		0.28		V
Forward Voltage		I _F =10A, T _J =25°C		0.44		V
		I _F =10A, T _J =125°C		0.36		V
		I _F =20A, T _J =25°C		0.54	0.58	V
		I _F =20A, T _J =125°C		0.51	0.53	V
Poverse Current (Note 1)	,	V _R =50V, T _J =25°C		150	500	μΑ
Reverse Current (Note 1)	I _{RM}	V _R =50V, T _J =125°C		20	100	mA

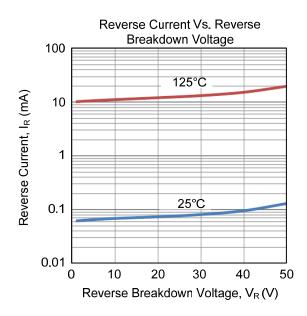
Notes: 1. Short duration pulse test used to minimize self-heating effect.

2. Thermal resistance junction to case mounted on heatsink.

MGBR20V50

■ TYPICAL CHARACTERISTICS





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